IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No
Priority Filing Date June 10, 2003
Inventor Leonard Forbes
Assignee Micron Technology, Inc.
Priority Group Art Unit
Priority Examiner V. Nguyen
Attorney's Docket No MI22-2481
Title: Computer Systems, Processes For Turning A SRAM Cell Off, and Processes For
Writing A SRAM Cell and Processes for Reading Data Grown at SRAM Self

INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, your attention is directed to the United States patents and other references listed on the attached Form PTO-1449. No admission is made regarding whether all the submitted references are prior art.

The listed references were cited by, or submitted to, the Office in the parent, co-pending application of the above-identified application. The above-identified application is a divisional application of co-pending application Serial No. 10/459,064, filed July 10, 2003. Such prior disclosure is sufficient for the above-identified application as far as copies of the references are concerned. 37 C.F.R. § 1.98(d) and MPEP § 609(2).

Citation of these references is respectfully requested.

Respectfully submitted,

Dated: 4/6/04

James D. Shaurette Reg. No. 39,833

By:

								==			
Form PTO-144	9		ATTY. DOCKET NO MI22-2481		PRIORITY SERIAL NO. 10/459,064						
		LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)				APPLICANT Leonard Forbes					
						PRIORITY FILING DATE July 10, 2003			PRIORITY GROUP 2818		
				U.S. PAT	TENT DOCUMENTS						
*Examiner Initial		Document Number	Date		Name			Class Subo		oclas Filing Date If Appropriate	
	AA	6,128,216	10/03/00	Noble, Jr. et	Noble, Jr. et al.						
	AB	5,825,687	10/20/98	Yin	Yin						
	AC	6,287,913 B1	09/11/01	Agnello et al	l.						
55 15 17	AD	5,754,468	05/19/98	Hobson	Hobson						
	AE	6,104,045	08/15/00 Forbes et al.								
	AF	6,225,165 B1	05/01/01	Noble, Jr. et al. EL979949726							
	AG	6,342,718 B1	01/29/02	Noble					,		
	АН	6,194,759 B1	02/2001	Sano et al.							
	Al	6,459,113 B1	10/01/02	Moribara et	Moribara et al. Moribara et al.						
	AJ	2002/0028550 A1	03/07/02	Moribara et							
	AK	6,011,726	01/04/00	Batson et al.							
				FOREIGN F	PATENT DOCUMENT	S					
		Document	Date	Country			Class	Subclass	Abstract		
		Number						Yes	No		
	AL	10-335488	12/1998	Japan							x
	AM	JP02001308298 A	11/02/01_	Japan	Japan					х	
	AN				·			<u> </u>			
	AO			<u> </u>			<u> </u>	<u> </u>			
	AP			<u> </u>				L			
		C	THER REFERE	ENCES (includir	ng Author, Title, Date,	Pertinent Pages, Etc.)					
AR Lage et al., "Advanced SRAM technology - the rate between 4T and 6T cells," Abstract (Web address - http://pluto.ei.org,										,	
		Technical Digest - Proceedings of the 1996 IEEE International Electron Devices Meeting Dec. 8-11, 1996.									
	AS Noda et al., "A 1.9-µm² Loadless CMOS Four-Transistor SRAM Cell in a 0.18-µm Logic Technology", 1998, ULSI Device Development Laboratories, NEC Corporation, Japan, 5 pages.										
										-	
	AT										
EXAMINER					DATE CONSIDERE	D					
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.											

Sheet 2 of 2 Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY. DOCKET NO. PRIORITY SERIAL NO. PATENT AND TRADEMARK OFFICE MI22-2481 10/459,064 LIST OF ART CITED BY APPLICANT APPLICANT Leonard Forbes (Use several sheets if necessary) PRIORITY FILING DATE PRIORITY GROUP July 10, 2003 2818 U.S. PATENT DOCUMENTS *Examiner Document Date Name Class Subclass Filing Date Initial Number If Appropriate AΑ 6,184,588 2/2001 Kim et al. ΑB 5,774,392 6/1998 Kraus et al. AC 6,212,102 4/2001 Georgakos et al. AD 6,265,266 7/2001 Dejenfelt et al. 2/1995 ΑE 5,388,068 Ghoshal et al. AF 5,754,010 5/1998 Caravella et al. E1.979949726 6,519,197 B2 2/11/2003 AG Forbes ΑН 2003/0076721 A1 4/24/2003 Forbes ΑI 6,275,433 B1 8/14/2001 Forbes 6,448,601 B1 9/10/2002 Forbes et al. 7/18/2000 AK 6,090,648 Reedy et al. FOREIGN PATENT DOCUMENTS Date Class Subclass Document Country **Abstract** Number Yes No AL AM ΑN ΑO AP OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.) AR AS

EXAMINER DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include

copy of this form with next communication to applicant.

ΑT